


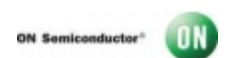






	<h2 style="color: #E67E22;">FQP19N20C_F080</h2> <p><b>Hersteller-Teilenummer:</b> <a href="#">FQP19N20C_F080</a></p> <p><b>Hersteller / Marke:</b> Fairchild/ON Semiconductor</p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 200V 19A TO-220</p> <p><b>Datenblätter:</b> <a href="#">1.FQP19N20C_F080.pdf</a> <a href="#">2.FQP19N20C_F080.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 2683 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
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<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Artikelnummer	<a href="#">FQP19N20C_F080</a>
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 200V 19A TO-220
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	2683 pcs Stock
VGS (th) (Max) @ Id	4V @ 250µA
Technologie	MOSFET (Metal Oxide)
Supplier Device-Gehäuse	TO-220-3
Serie	QFET®
Rds On (Max) @ Id, Vgs	170 mOhm @ 9.5A, 10V
Verlustleistung (max)	139W (Tc)
Verpackung	Tube
Verpackung / Gehäuse	TO-220-3
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Eingabekapazität (Ciss) (Max) @ Vds	1080pF @ 25V
Gate Charge (Qg) (Max) @ Vgs	53nC @ 10V
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	200V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	19A (Tc)

### Sie können auch interessiert

<p>sein:</p>  <p><b>FQP19N20L</b> Fairchild/ON Semiconductor MOSFET N-CH 200V 21A TO-220</p>	 <p><b>FQP19N20CTSTU</b> Fairchild/ON Semiconductor MOSFET N-CH 200V 19A TO-220</p>	 <p><b>FQP19N20C</b> Fairchild/ON Semiconductor MOSFET N-CH 200V 19A TO-220</p>	 <p><b>FQP19N20L</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 21A TO-220</p>
 <p><b>FQP19N20C MOS</b> FAIRCHILD FAIRCHILD TO-220</p>	 <p><b>FQP19N20C</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 19A TO-220</p>	 <p><b>FQP19N20CTSTU</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 19A TO-220</p>	 <p><b>FQP1N50</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 1.4A TO-220</p>

### FQP19N20C\_F080 Zugehöriges

Mehr

#### Schlüsselwort

Fairchild/ON Semiconductor	<a href="#">FQP19N20C_F080 Datenblatt</a>	<a href="#">FQP19N20C_F080-Datenblätter</a>	<a href="#">FQP19N20C_F080 PDF</a>	Fairchild/ON Semiconductor
<a href="#">FQP19N20C_F080 Electronic</a>	<a href="#">FQP19N20C_F080-Komponenten</a>	<a href="#">FQP19N20C_F080-Verteiler</a>	<a href="#">FQP19N20C_F080-Bild</a>	<a href="#">FQP19N20C_F080</a>
<a href="#">FQP19N20C_F080 Preis</a>	<a href="#">FQP19N20C_F080 Hersteller</a>	<a href="#">FQP19N20C_F080 Bild</a>	<a href="#">FQP19N20C_F080 Aktie</a>	<a href="#">FQP19N20C_F080-Teil</a>
<a href="#">FQP19N20C_F080 Neu</a>	<a href="#">FQP19N20C_F080 Original</a>	<a href="#">FQP19N20C_F080 garantiert</a>	<a href="#">FQP19N20C_F080 RFQ</a>	<a href="#">FQP19N20C_F080 Inventar</a>
				<a href="#">FQP19N20C_F080 Online bestellen</a>

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